

Description

The 74AHC32 provides provides four independent 2-input OR gates with standard push-pull outputs. The device is designed for operation with a power supply range of 2.0V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment.

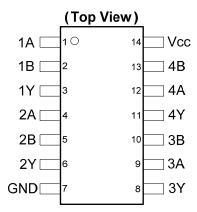
The gates perform the Boolean function:

$$Y = A + B$$
 or $Y = \overline{A \cdot B}$

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Outputs Sink or Source 8mA at V_{CC} = 4.5V
- **CMOS Low Power Consumption**
- Schmitt Trigger Action at All Inputs
- Inputs can be driven by 3.3V or 5.5V allowing for voltage translation applications.
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



SO-14 / TSSOP-14

Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- <1000ppm antimony compounds.

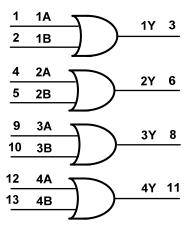
Click here for ordering information located at the end of datasheet



Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	V _{CC}	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
Α	В	Υ
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

Absolute Maximum Ratings (Note 4) (@TA = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
lık	Input Clamp Current V _I < -0.5V	-20	mA
I _{OK}	Output Clamp Current V _O < -0.5V	-20	mA
I _{OK}	Output Clamp Current V _O > V _{CC} +0.5V	25	mA
Io	Continuous Output Current -0.5V < V _O V _{CC} +0.5V	+/- 25	mA
Icc	Continuous Current Through V _{CC}	75	mA
I _{GND}	Continuous Current Through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Note:

^{4.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage		2.0	5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	Vcc	V
Δt/ΔV	Input Transition Rise or Fall Rate	V _{CC} = 3.0V to 3.6V		100	no/\/
ΔυΔν	input transition Rise of Fall Rate	V _{CC} = 4.5V to 5.5V		20	ns/V
T _A	Operating Free-Air Temperature		-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

O: mala al	Domenantan	Took Conditions		T _A = -40°	C to +85°C	T _A = -40°C	to +125°C	11=14
Symbol	Parameter	Test Conditions	V _{CC}	Min	Max	Min	Max	Unit
			2.0V	1.5		1.5		
VIH	High-Level Input Voltage		3.0V	2.1		2.1		V
			5.5V	3.85		3.85		
			2.0V		0.5		0.5	
V_{IL}	Low-Level Input Voltage		3.0V		0.9		0.9	V
			5.5V		1.65		1.65	
		I _{OH} = -50μA	2.0V	1.9		1.9		
	I _{OH} = -50μA	3.0V	2.9		2.9			
V_{OH}	High-Level Output Voltage	I _{OH} = -50μA	4.5V	4.4		4.4		V
		$I_{OH} = -4mA$	3.0V	2.48		2.40		
		I _{OH} = -8mA	4.5V	3.80		3.70		
		I _{OL} = 50μA	2.0V		0.1		0.1	
		I _{OL} = 50μA	3.0V		0.1		0.1	
V_{OL}	Low-Level Output Voltage	I _{OL} = 50μA	4.5V		0.1		0.1	V
	I _{OL} = 4mA	3.0V		0.44		0.55	1	
	I _{OL} = 8mA	4.5V		0.44		0.55		
lį	Input Current	V _I = GND to 5.5V	3.6V		±1		±2	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	3.6V		20		40	μA

Operating Characteristics

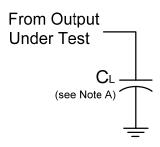
Parameter		Test Conditions	V _{CC} = 2.0V Typ	V _{CC} = 3.3V Typ	V _{CC} = 5V Typ	Unit
C _{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	9.7	11.0	14.9	pF
Ci	Input Capacitance	$V_i = V_{CC} - or$ GND	4.0	4.0	4.0	pF



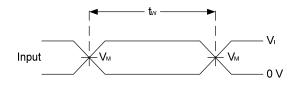
Switching Characteristics

Symbol	Parameter	Test	V	1	Γ _A = +25°0	3	-40°C to	o +85°C	-40°C to	+125°C	Unit
Syllibol	Farameter	Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Oilit
		Figure 1	3.0V to 3.6V	0.5	4.5	7.9	0.5	9.5	0.5	10.0	
	Propagation	$C_L = 15pF$	4.5V to 5.5V	0.5	3.2	5.5	0.5	6.5	0.5	7.0	20
t _{PD}	Delay A _N to Y _N	Figure 1	3.0V to 3.6V	0.5	6.0	11.4	0.5	13.0	0.5	14.5	ns
		$C_L = 50pF$	4.5V to 5.5V	0.5	4.5	7.5	0.5	8.5	0.5	9.5	

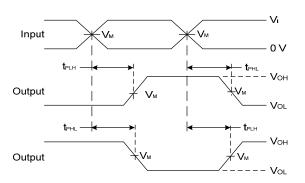
Parameter Measurement Information



V	Inp	outs	V		
V _{CC}	VI	t _r /t _f	V _M	C _L	
3.3V -3.6V	V _{CC}	3ns	V _{CC} /2	15pF, 50pF	
4.5V to 5.5V	V _{CC}	3ns	V _{CC} /2	15pF, 50pF	



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

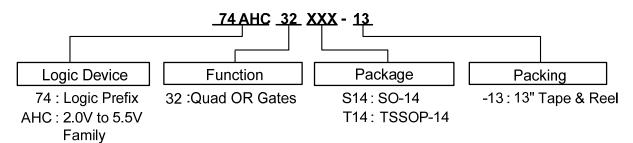
Figure 1. Load Circuit and Voltage Waveforms

Notes: A . Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$



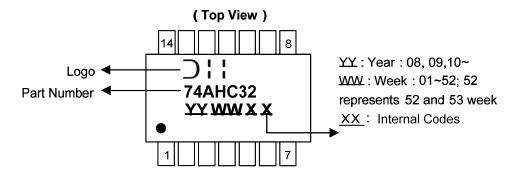
Ordering Information



Device	Backage Code	Dookoging	7" Tape	and Reel
Device	Package Code	Packaging	Quantity	Part Number Suffix
74AHC32S14-13	S14	SO-14	2500/Tape & Reel	-13
74AHC32T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Marking Information

(1) SO-14, TSSOP-14



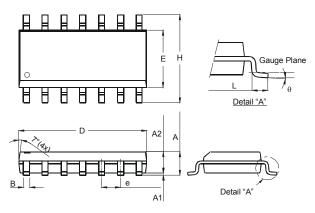
Part Number	Package
74AHC32S14	SO-14
74AHC32T14	TSSOP-14



Package Outline Dimensions (All dimensions in mm.)

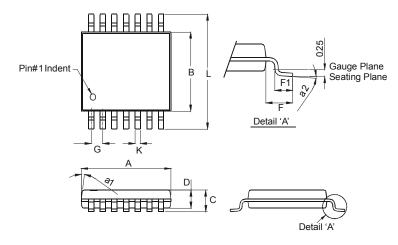
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14					
Dim	Min	Max				
Α	1.47	1.73				
A1	0.10	0.25				
A2	1.45	Тур				
В	0.33	0.51				
D	8.53	8.74				
Е	3.80	3.99				
е	1.27	Тур				
Н	5.80	6.20				
L	0.38	1.27				
θ	0° 8°					
All Di	All Dimensions in mm					

Package Type: TSSOP-14



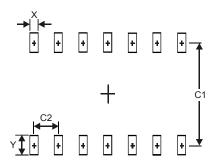
T	TSSOP-14					
Dim	Min	Max				
a1	7° (4X)				
a2	0°	8°				
Α	4.9	5.10				
В	4.30	4.50				
O		1.2				
D	8.0	1.05				
F	1.00	Тур				
F1	0.45	0.75				
O	0.65	Тур				
K	0.19	0.30				
L 6.40 Typ						
All Dimensions in						
	mm					



Suggested Pad Layout

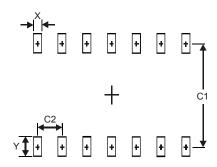
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

www.diodes.com



Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию.

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России, а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научноисследовательскими институтами России.

С нами вы становитесь еще успешнее!

Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,

Промышленная ул, дом № 19, литера Н,

помещение 100-Н Офис 331